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NXP Semiconductors/Freescale Semiconductor, Inc. BTA410-800CT,127

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BTA410-800CT 3Q Hi-Com Triac 13 June 2014

Product data sheet

1. **General description**

Planar passivated high commutation three quadrant triac in a SOT78 (TO-220AB) plastic package intended for use in circuits where high static and dynamic dV/dt and high dI/dt can occur. This "series CT" triac will commutate the full RMS current at the maximum rated junction temperature (T_{i(max)} = 150 °C) without the aid of a snubber. It is used in applications where "high junction operating temperature capability" is required.

2. Features and benefits

- 3Q technology for improved noise immunity
- High commutation capability with maximum false trigger immunity
- High immunity to false turn-on by dV/dt •
- High junction operating temperature capability
- High voltage capability •
- Less sensitive gate for high noise immunity
- Planar passivated for voltage ruggedness and reliability
- Triggering in three quadrants only

Applications 3.

- Applications subject to high temperature
- Electronic thermostats (heating and cooling) •
- Motor controls e.g. washing machines and vacuum cleaners •
- Rectifier-fed DC inductive loads e.g. DC motors and solenoids •

Quick reference data 4.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DRM}	repetitive peak off- state voltage			-	-	800	V
I _{TSM}	non-repetitive peak on- state current	full sine wave; $T_{j(init)} = 25 \text{ °C}$; $t_p = 20 \text{ ms}$; Fig. 4; Fig. 5		-	-	100	A
I _{T(RMS)}	RMS on-state current	full sine wave; T _{mb} ≤ 131 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u>		-	-	10	A
Static charac	teristics	· · · · · · · · · · · · · · · · · · ·	·				,
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u>		2	-	35	mA







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Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
		V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u>	2	-	35	mA
		V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u>	2	-	35	mA
Dynamic cl	haracteristics	· · · ·				
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit	500	-	-	V/µs
dl _{com} /dt	rate of change of commutating current	$\label{eq:VD} \begin{split} V_D &= 400 \text{ V}; \text{T}_{j} = 150 ^\circ\text{C}; \text{I}_{\text{T}(\text{RMS})} = 10 \text{ A}; \\ \text{d} V_{\text{com}}/\text{d} \text{t} &= 20 \text{V}/\mu\text{s}; \text{ (snubberless condition); gate open circuit} \end{split}$	8	-	-	A/ms

5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	T1	main terminal 1	mb	T2
2	Т2	main terminal 2	$2 \circ 4$	Sym051
3	G	gate		
mb	Τ2	mounting base; main terminal 2		
			TO-220AB (SOT78)	

6. Ordering information

Table 3. Ordering inf	formation		
Type number	Package		
	Name	Description	Version
BTA410-800CT	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78

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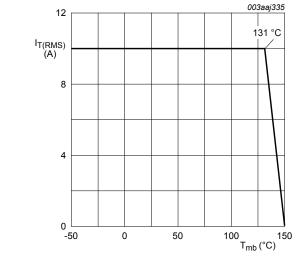
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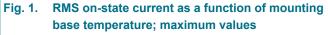
7. Limiting values

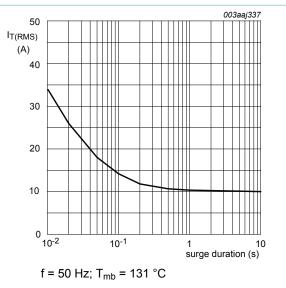
Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	800	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _{mb} ≤ 131 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u>	-	10	A
I _{TSM}	non-repetitive peak on-state current	full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4</u> ; <u>Fig. 5</u>	-	100	A
		full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms	-	110	A
l ² t	I ² t for fusing	t _p = 10 ms; sine-wave pulse	-	50	A ² s
dI _T /dt	rate of rise of on-state current	I_T = 20 A; I_G = 0.2 A; dI_G/dt = 0.2 A/µs	-	100	A/µs
I _{GM}	peak gate current		-	2	А
P _{GM}	peak gate power		-	5	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.5	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C







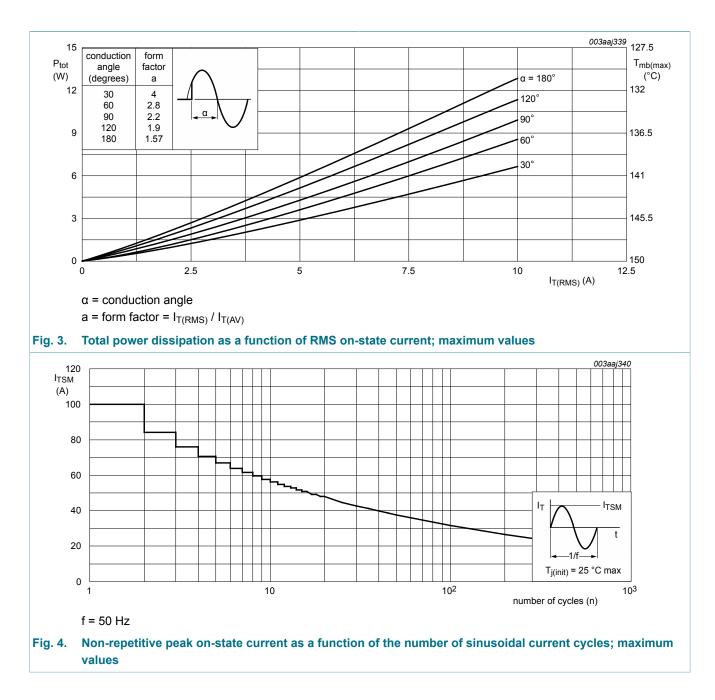


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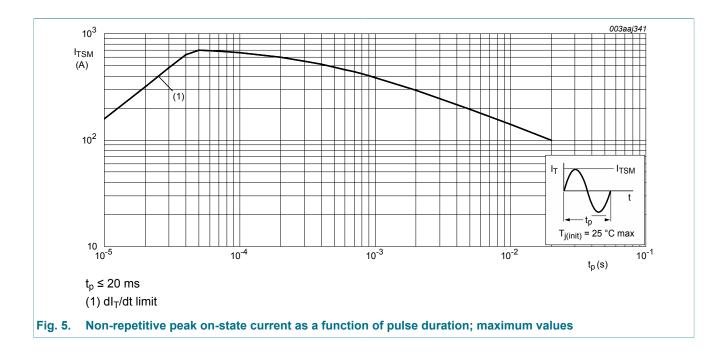


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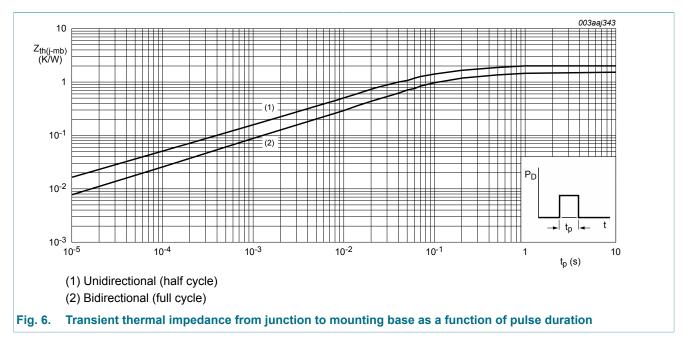


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8. Thermal characteristics

Table 5. T	hermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance	full cycle; <u>Fig. 6</u>	-	-	1.5	K/W
	from junction to mounting base	half cycle; Fig. 6	-	-	2	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	-	60	-	K/W



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9. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u>	2	-	35	mA
		V_D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u>	2	-	35	mA
		V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u>	2	-	35	mA
IL	latching current	$V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2+ G+};$ T _j = 25 °C; <u>Fig. 8</u>	-	-	50	mA
		$V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2+ G-};$ T _j = 25 °C; Fig. 8	-	-	60	mA
		$V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2- G-};$ T _j = 25 °C; <u>Fig. 8</u>	-	-	50	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	-	35	mA
V _T	on-state voltage	I _T = 15 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.3	1.6	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; Fig. 11	-	0.8	1	V
		V _D = 400 V; I _T = 0.1 A; T _j = 150 °C; Fig. 11	0.25	0.4	-	V
I _D	off-state current	V _D = 800 V; T _j = 150 °C	-	0.4	2	mA
Dynamic cł	naracteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit	500	-	-	V/µs
dl _{com} /dt	rate of change of commutating current	$V_{D} = 400 \text{ V}; \text{T}_{\text{j}} = 150 \text{ °C}; \text{I}_{\text{T}(\text{RMS})} = 10 \text{ A};$ $dV_{\text{com}}/dt = 20 \text{ V}/\mu\text{s}; \text{ (snubberless condition); gate open circuit}$	8	-	-	A/ms
		$V_{D} = 400 \text{ V}; \text{T}_{\text{j}} = 150 ^{\circ}\text{C}; \text{I}_{\text{T}(\text{RMS})} = 10 \text{ A}; \\ \text{d} \text{V}_{\text{com}}/\text{d} \text{t} = 10 \text{ V}/\mu\text{s}; \text{ gate open circuit}$	13	-	-	A/ms
		V_D = 400 V; T _j = 150 °C; I _{T(RMS)} = 10 A; dV _{com} /dt = 1 V/µs; gate open circuit	20	-	-	A/ms

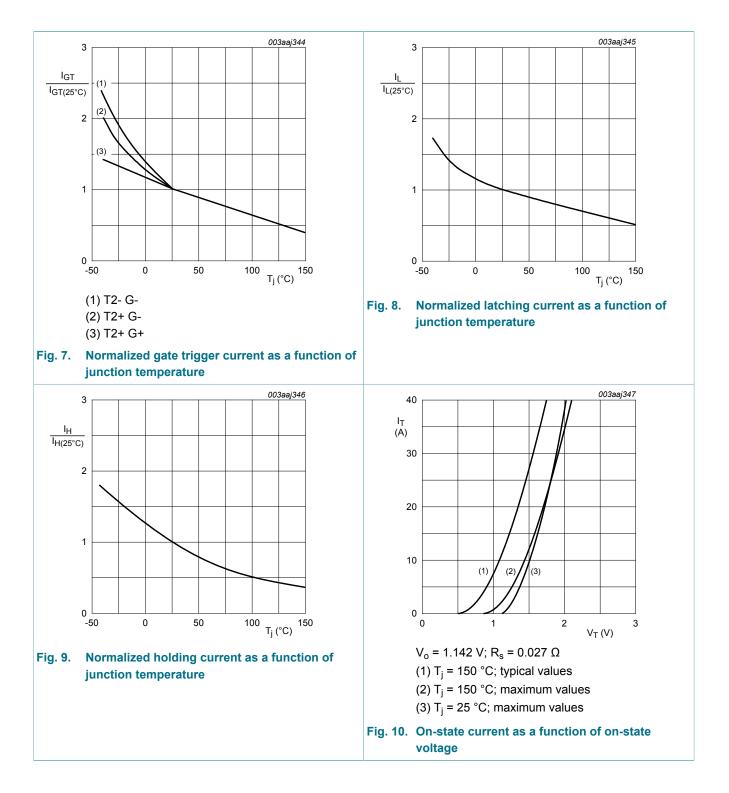


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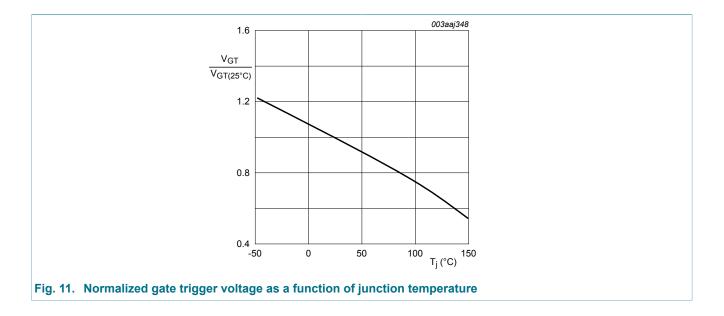
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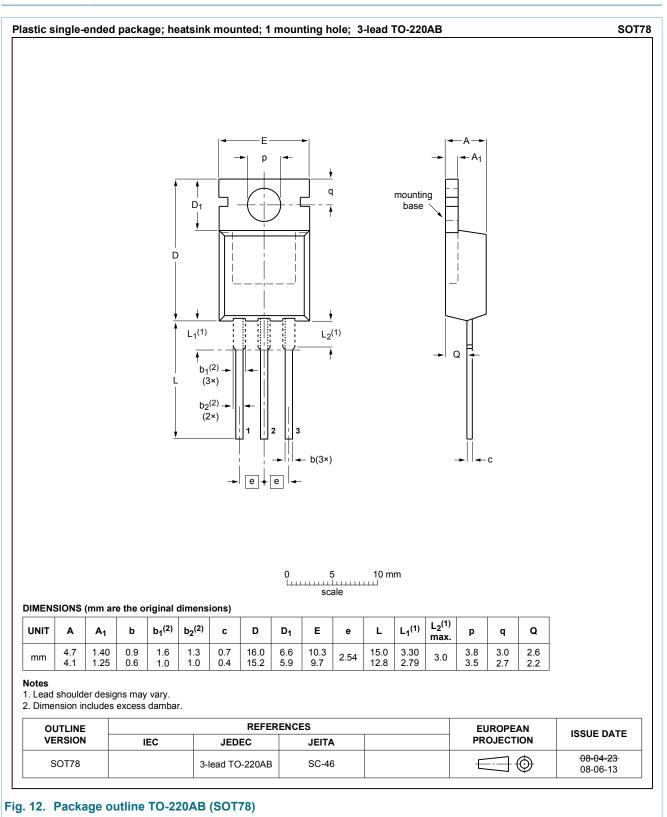




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10. Package outline



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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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